CS223-4M CS223-4N

# SURFACE MOUNT SILICON CONTROLLED RECTIFIERS 4.0 AMP, 600 AND 800 VOLT



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# **DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CS223-4M and CS223-4N are epoxy molded SCRs designed for sensing circuit applications and control systems.

**MARKING: FULL PART NUMBER** 



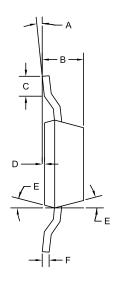
<b>MAXIMUM RATINGS:</b> (T <sub>C</sub> =25°C unless otherwise noted) Peak Repetitive Off-State Voltage		SYMBOL V <sub>DRM,</sub> V <sub>RRM</sub>	CS223-4M 600	<b>CS223-4N</b> 800	UNITS V
RMS On-State Current (T <sub>C</sub> =85°C)		I <sub>T</sub> (RMS)	4.0		Α
Peak One Cycle Surge, t=10ms		ITSM	30		Α
I <sup>2</sup> t Value for Fusing, t=10ms		I <sup>2</sup> t	4.5		$A^2s$
Peak Gate Powe	er, tp=20µs	P <sub>GM</sub>	3.	0	W
Average Gate Power Dissipation PG(A)		P <sub>G</sub> (AV)	0.2		W
Peak Gate Current, tp=20µs		<sup>I</sup> GM	1.2		Α
Critical Rate of Rise of On-State Current		di/dt	50		A/µs
Operating Junction Temperature		$T_J$	-50 to +125		°C
Storage Temperature		T <sub>stg</sub>	-50 to +150		°C
Thermal Resistance		$\Theta_{\sf JA}$	62.5		°C/W
ELECTRICAL C SYMBOL IDRM, IRRM	CHARACTERISTICS: (T <sub>C</sub> =25°C unless oth TEST CONDITIONS Rated $V_{DRM}$ , $V_{RRM}$ , $R_{GK}$ =1.0K $\Omega$	erwise noted) MIN	TYP	<b>MAX</b> 10	<b>UNITS</b> μΑ
I <sub>DRM</sub> , I <sub>RRM</sub>	Rated V <sub>DRM</sub> , V <sub>RRM</sub> , R <sub>GK</sub> =1.0KΩ, T <sub>C</sub> =		100	μΑ	
l <sub>GT</sub>	$V_D$ =12V, $R_L$ =10 $\Omega$	20	38	200	μΑ
lΗ	$I_T$ =50mA, $R_{GK}$ =1.0K $\Omega$		1.0	2.0	mA
$V_{GT}$	$V_D$ =12V, $R_L$ =10 $\Omega$		0.55	0.8	V
$V_{TM}$	I <sub>TM</sub> =8.0A, tp=380μs		2.0	2.2	V
dv/dt	$V_{D}^{=2}/_{3} V_{DRM}, R_{GK}^{=1.0K\Omega}, T_{C}^{=125^{\circ}C}$	10			V/µs

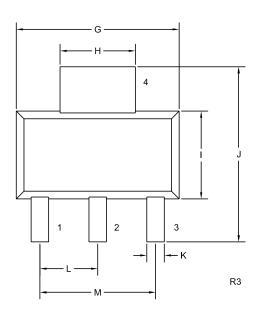
### CS223-4M CS223-4N

# **SURFACE MOUNT** SILICON CONTROLLED RECTIFIERS 4.0 AMP, 600 AND 800 VOLT



# **SOT-223 CASE - MECHANICAL OUTLINE**





### LEAD CODE:

- 1) Cathode
- 2) Anode
- 3) Gate 4) Anode

### MARKING: **FULL PART NUMBER**

DIMENSIONS							
	INCHES		MILLIMETERS				
SYMBOL	MIN	MAX	MIN	MAX			
Α	0°	10°	0°	10°			
В	0.059	0.071	1.50	1.80			
С	0.018		0.45				
D	0.000	0.004	0.00	0.10			
Е	15°		15°				
F	0.009	0.014	0.23	0.35			
G	0.248	0.264	6.30	6.70			
Н	0.114	0.122	2.90	3.10			
	0.130	0.146	3.30	3.70			
J	0.264	0.287	6.70	7.30			
K	0.024	0.033	0.60	0.85			
Ĺ	0.091		2.30				
М	0.181		4.60				
COT 202 (DEV. D2)							

SOT-223 (REV: R3)

R3 (1-June 2015)

### **OUTSTANDING SUPPORT AND SUPERIOR SERVICES**



### PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

### **DESIGNER SUPPORT/SERVICES**

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2<sup>nd</sup> day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- · Special wafer diffusions
- · PbSn plating options
- Package details
- · Application notes
- · Application and design sample kits
- · Custom product and package development

#### **CONTACT US**

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